

Faculty of Engineering
School of Photovoltaic and Renewable Energy Engineering



Application of the Intrinsic-Adjusted Single Diode Model to Production Data

PVPMC, Albuquerque, USA 12-14 May 2026

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A Dark Past



- Sinton PCD Tester: The *most* common tool in any photovoltaic research laboratory
- Used to measure carrier recombination lifetimes
- Less recombination → Higher device efficiencies

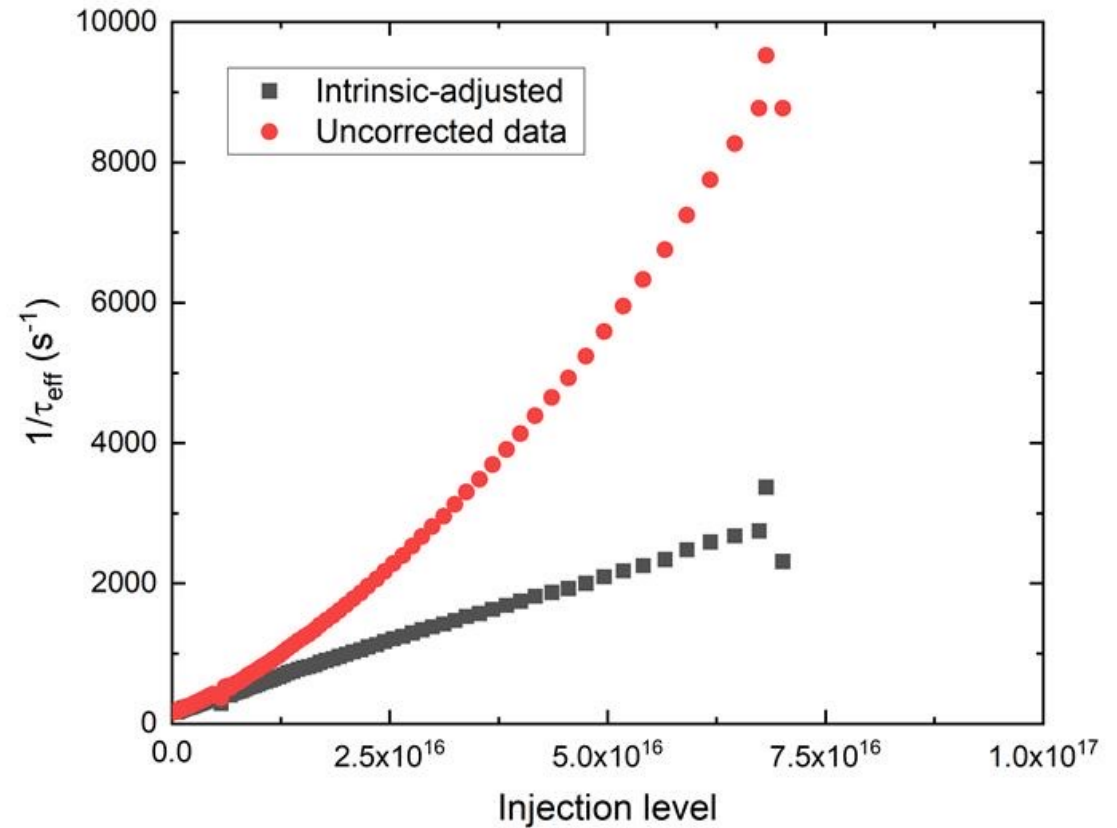
R.A. Sinton, A. Cuevas, *Appl. Phys. Lett.* **69**, 2510 (1996).

<https://www.sintoninstruments.com/products/>

A Dark Past



B. Hoex, *et al. Applied Physics Letters* 91 (2007).



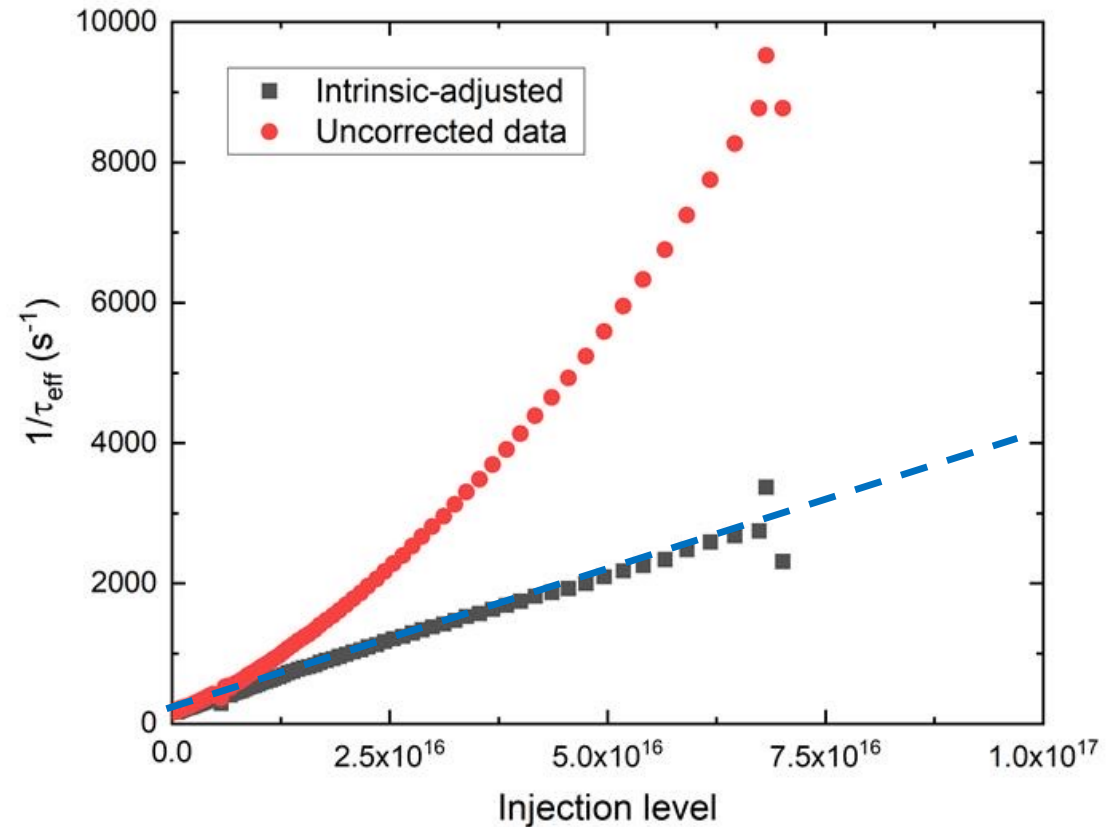
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$$I_{cell} = I_{ph} - I_0 \left[e^{\frac{V_{cell} + I_{cell} R_{S,cell}}{nV_{th}}} - 1 \right] - \frac{V_{cell} + I_{cell} R_{S,cell}}{R_{SH,cell}}$$

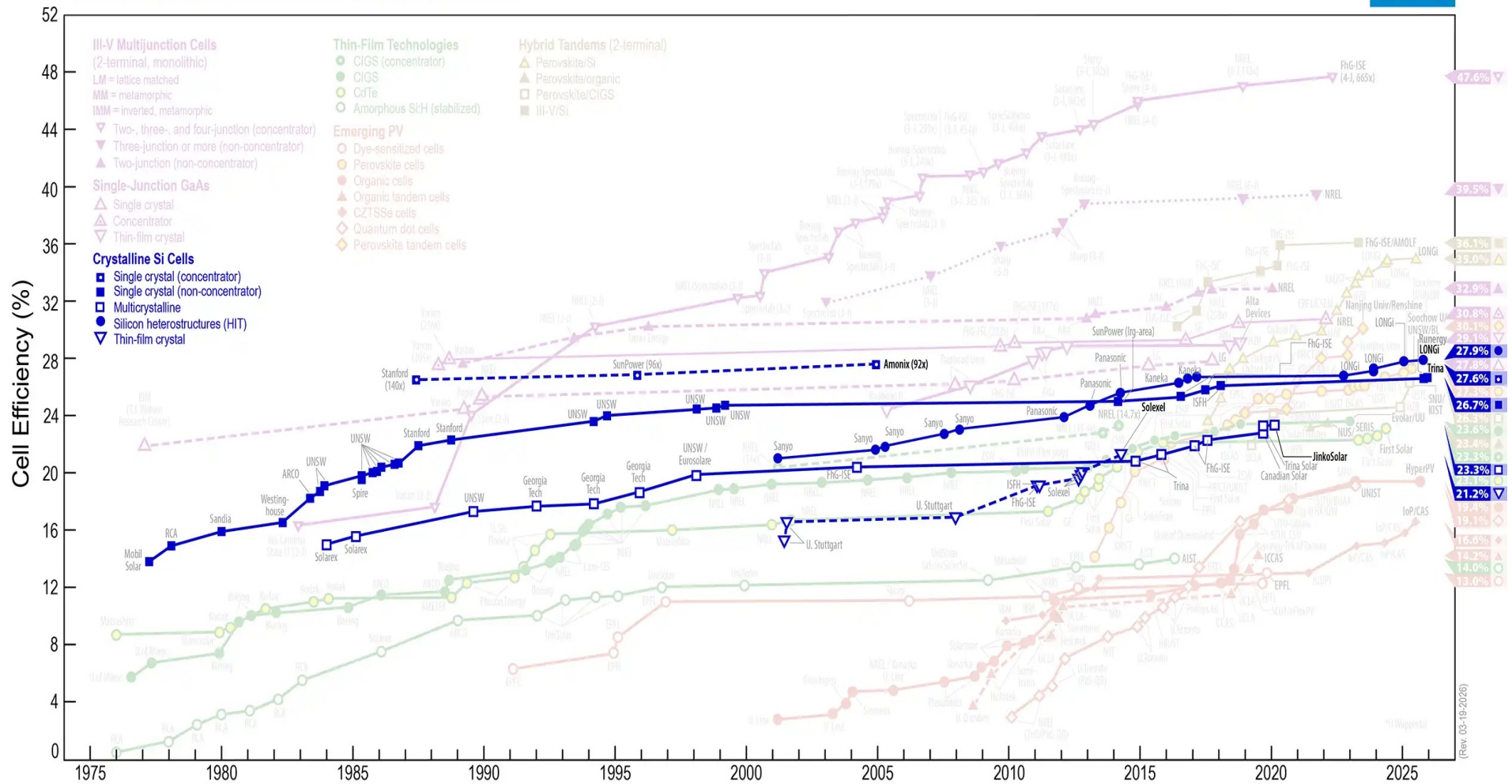
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A Bright Future

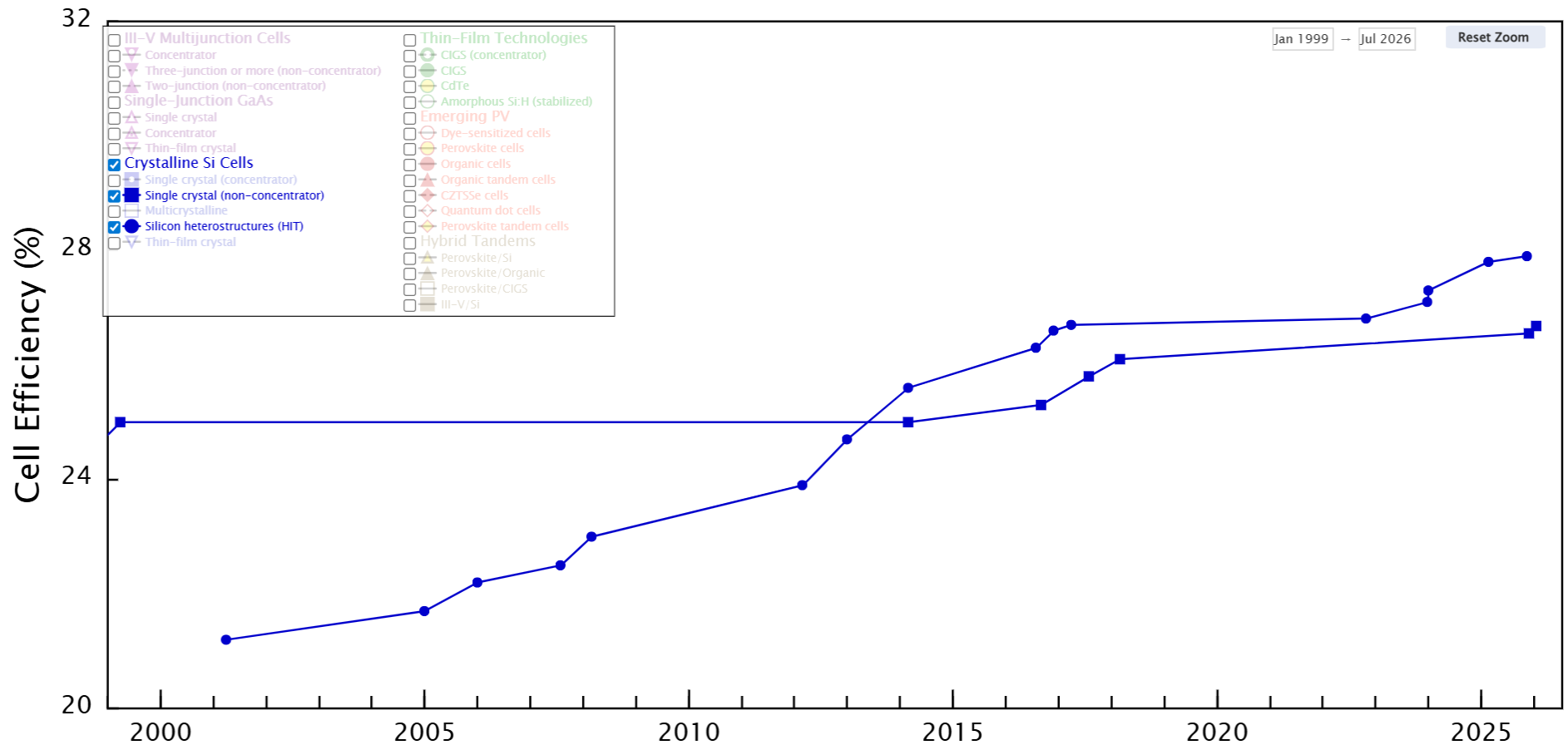
Best Research-Cell Efficiencies

NATIONAL LABORATORY OF THE ROCKIES



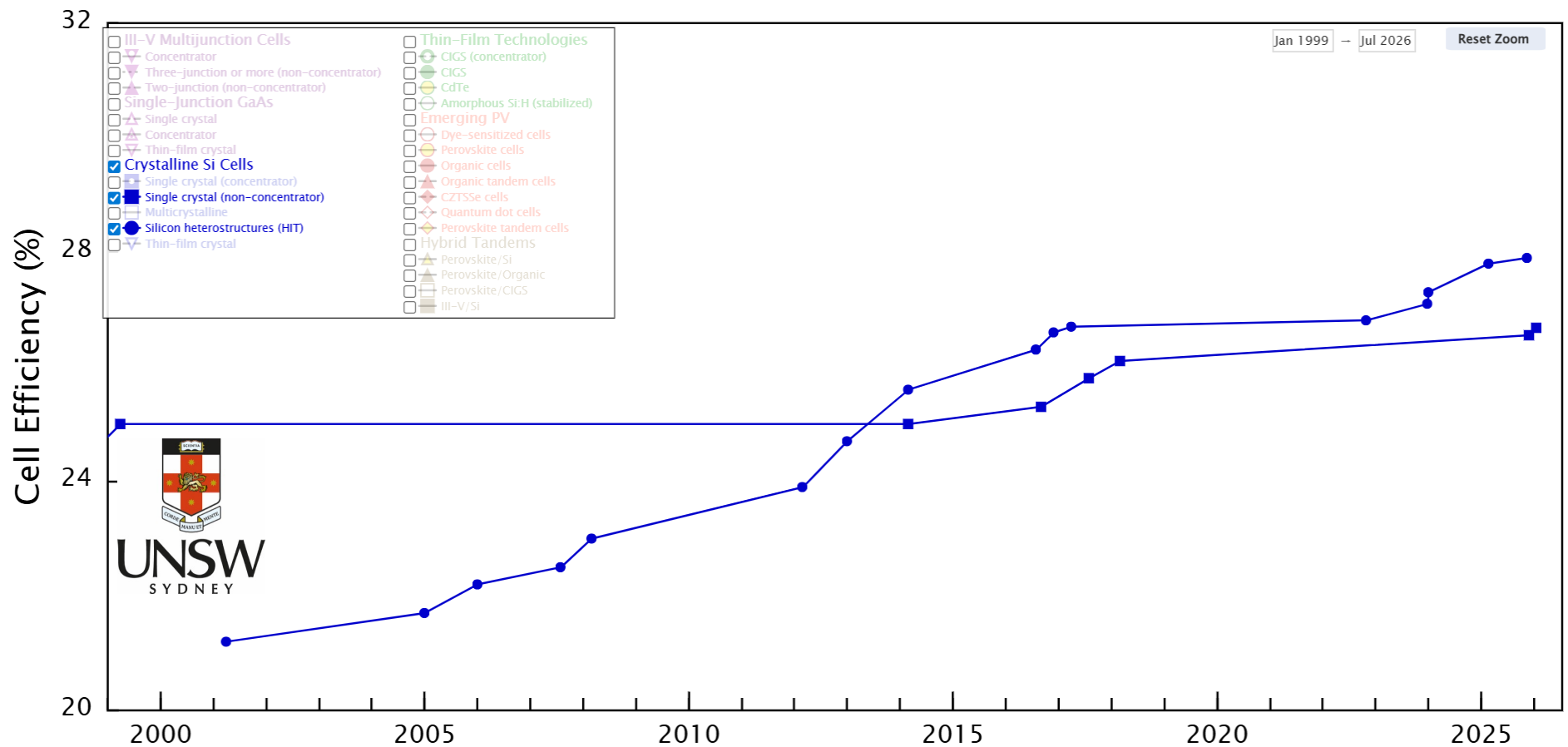
Source: <https://www.nlr.gov/pv/cell-efficiency>

A Bright Future



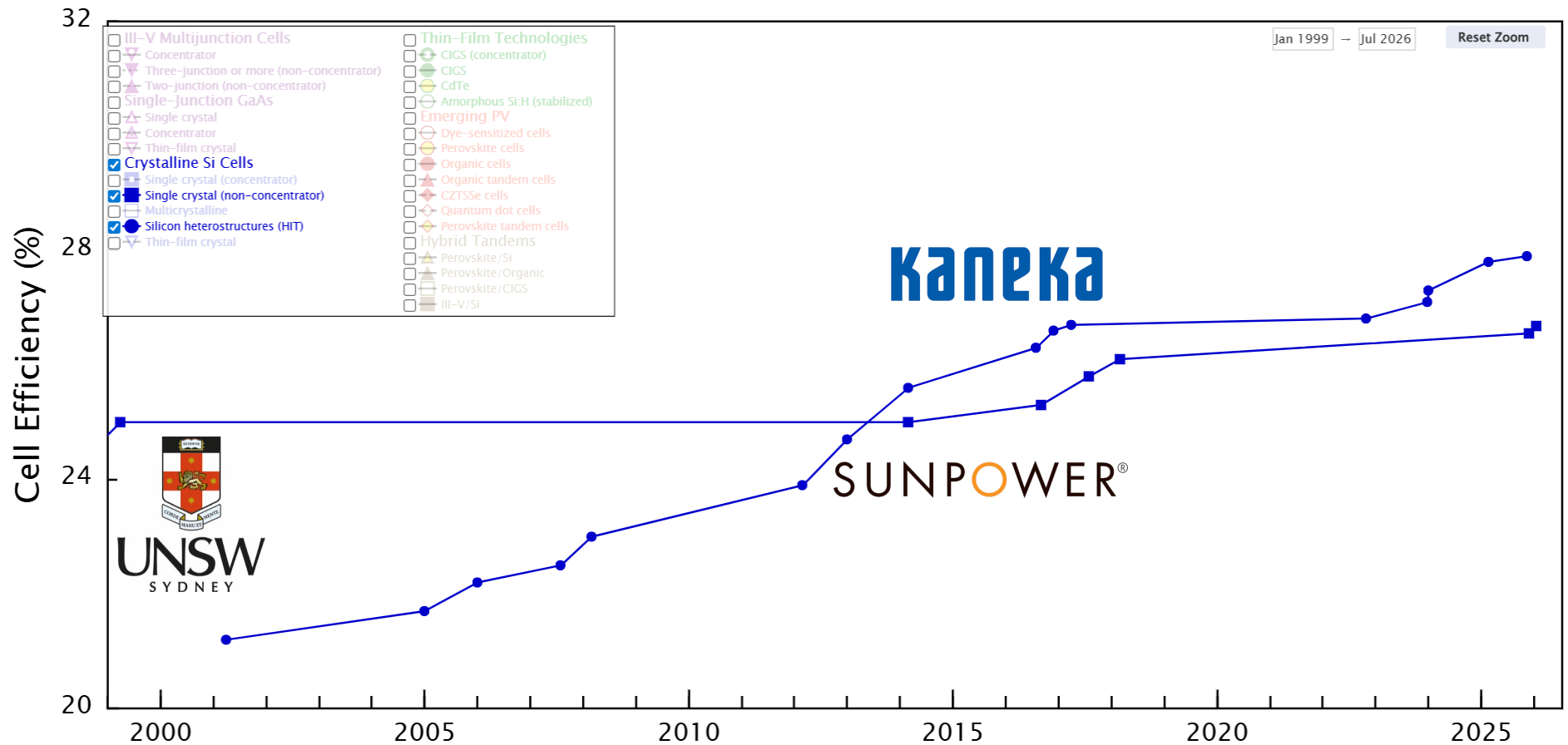
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A Bright Future



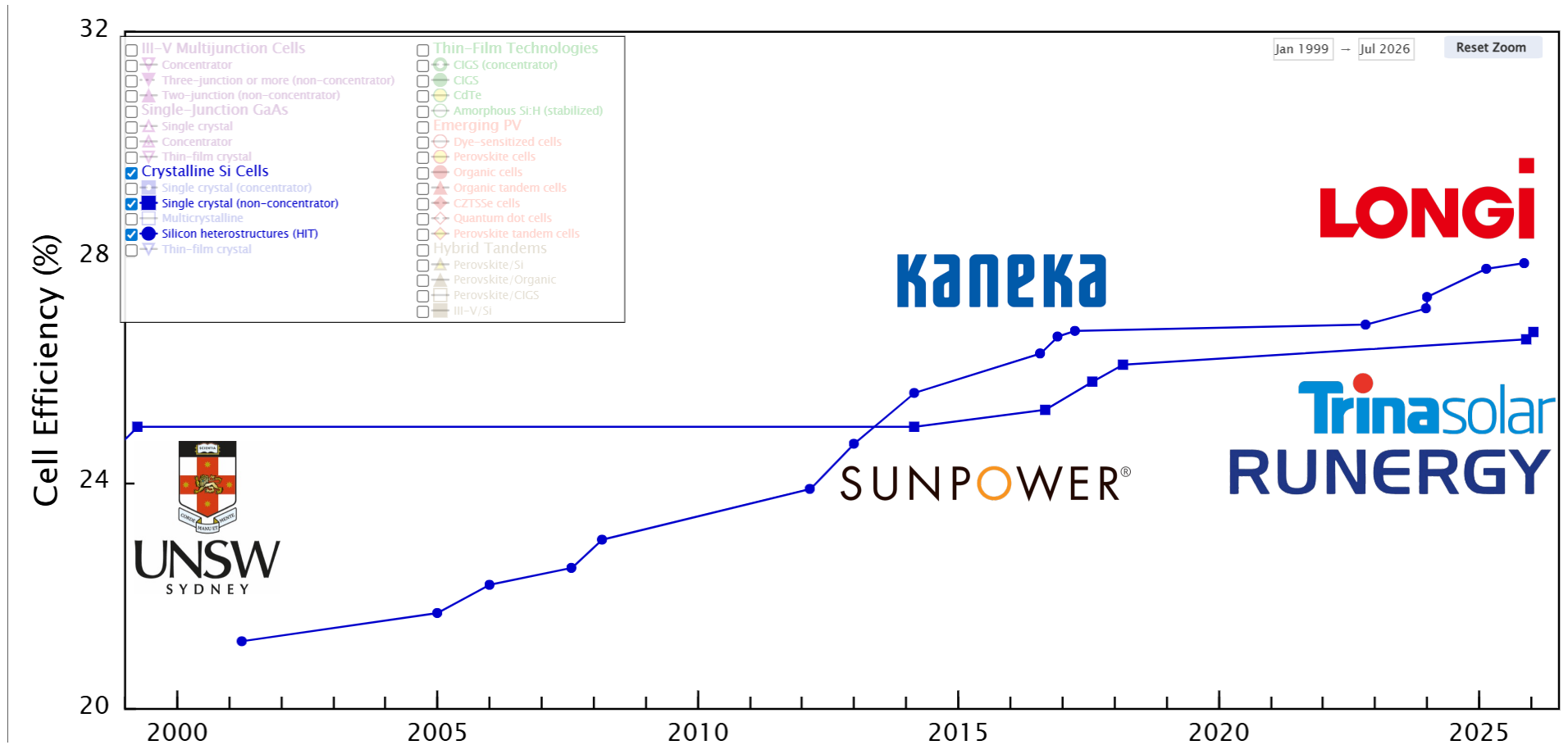
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A Bright Future



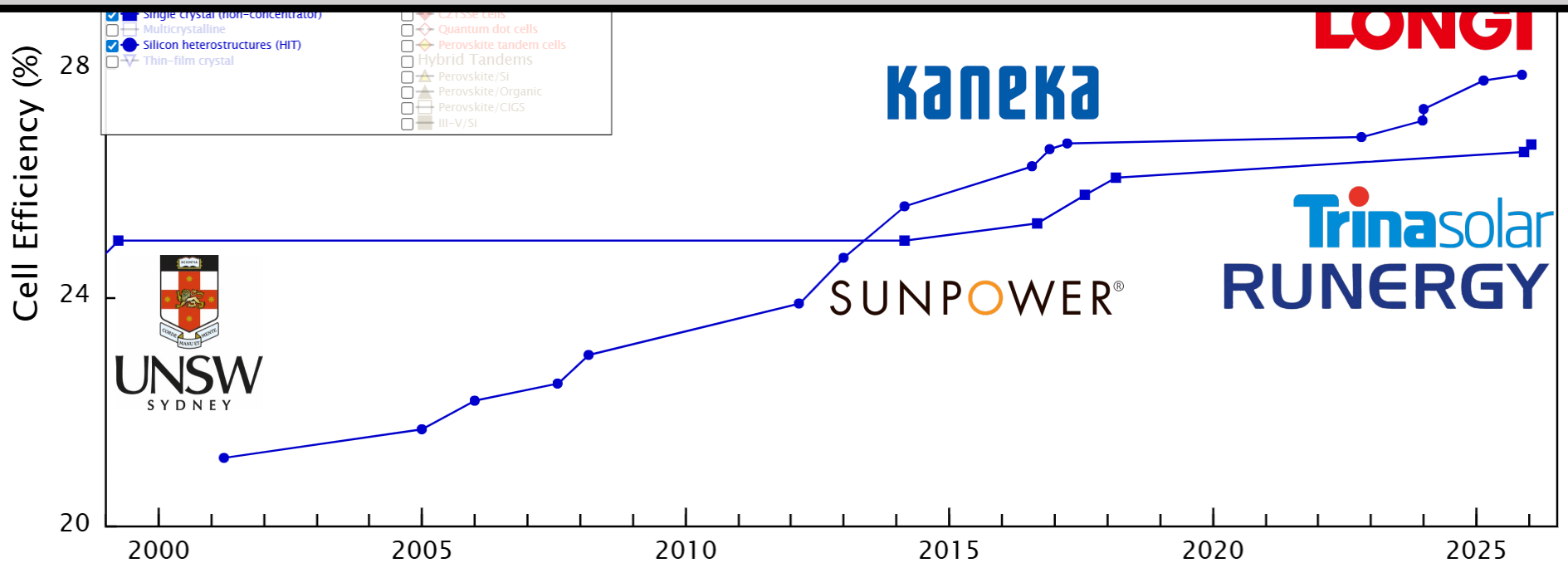
Source: <https://www.nlr.gov/pv/cell-efficiency>

A Bright Future



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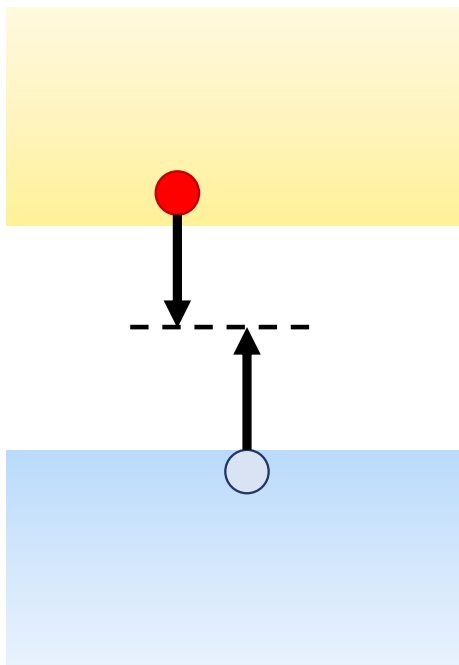
A Bright Future



Source: <https://www.nlr.gov/pv/cell-efficiency>

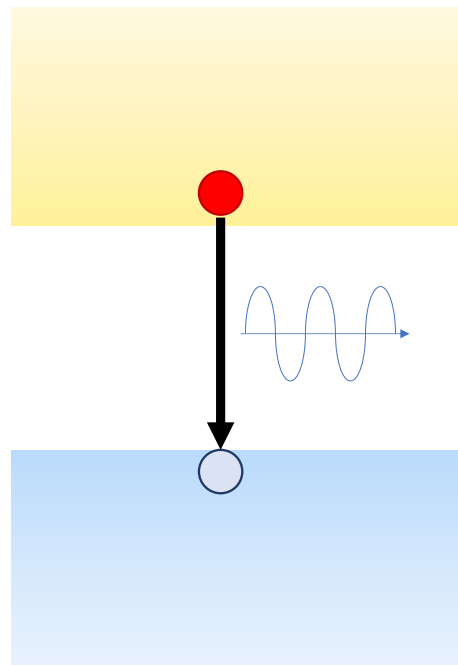
Recombination in Silicon

Shockley-Read Hall



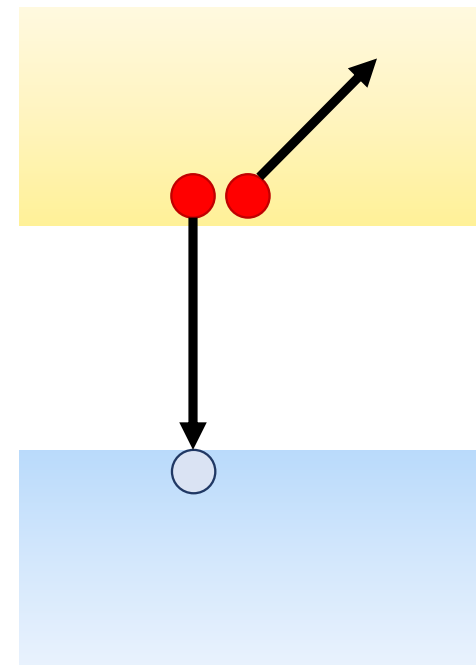
$$\propto np$$

Radiative



$$\propto np$$

Auger

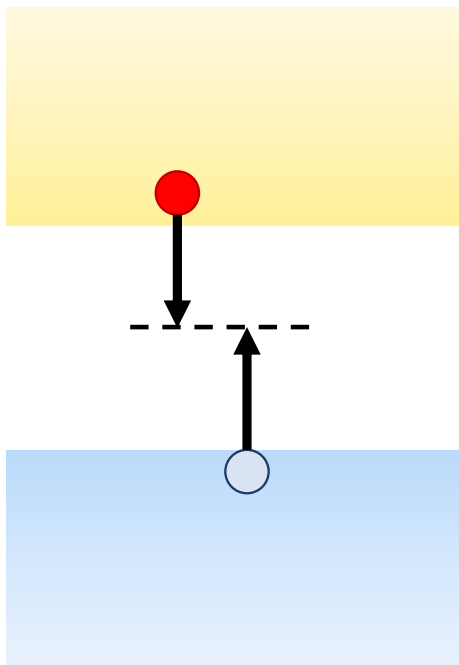


$$\propto n^2p + np^2$$

Recombination in Silicon

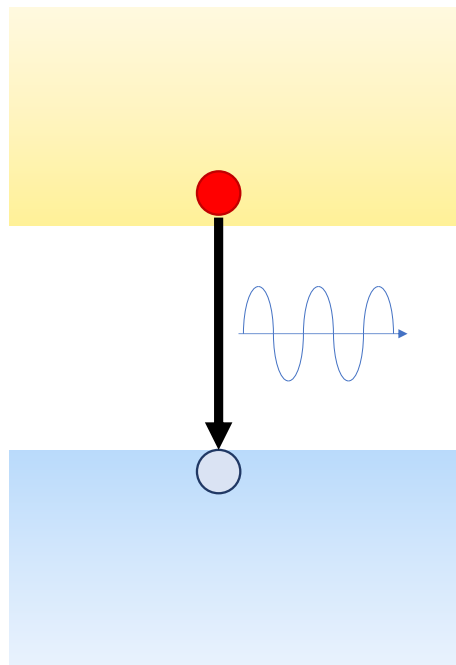
Intrinsic Recombination

Shockley-Read Hall



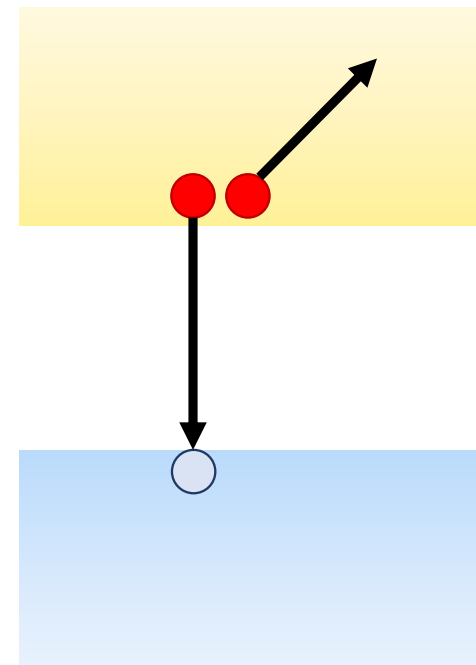
$$\propto np$$

Radiative



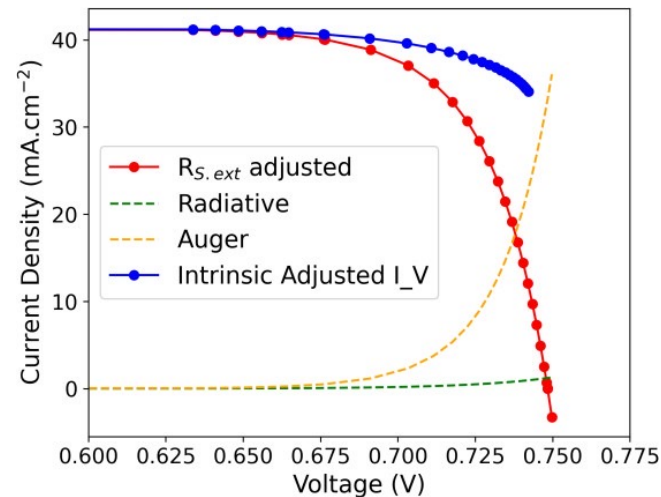
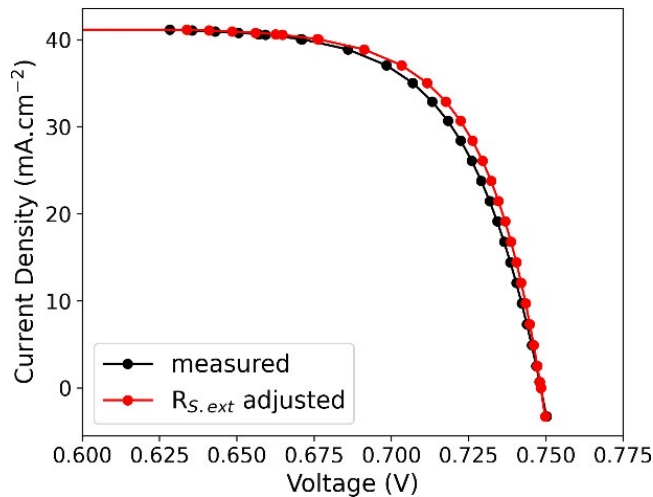
$$\propto np$$

Auger



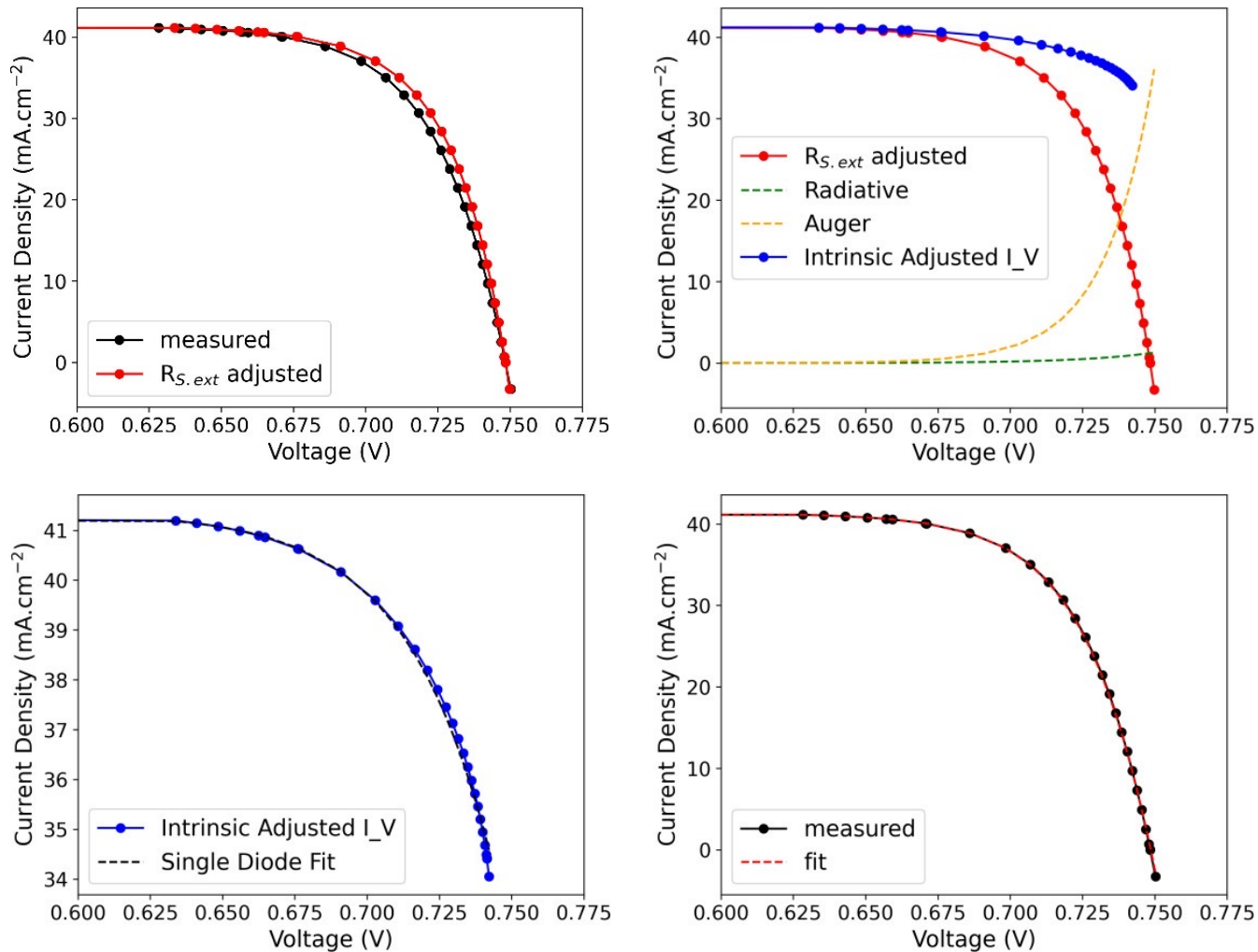
$$\propto n^2p + np^2$$

Adjusting the Single-Diode Model



Hamer, P, *et al.* "The intrinsic adjusted single-diode model: Solid State Physics meets accurate yield simulation." *Solar Energy Materials and Solar Cells* 300 (2026): 114218.

Adjusting the Single-Diode Model



Hamer, P, *et al.* "The intrinsic adjusted single-diode model: Solid State Physics meets accurate yield simulation." *Solar Energy Materials and Solar Cells* 300 (2026): 114218.

Calculating Intrinsic Recombination

$$I = I_{ph} - I_{rad}(V_{adj}, w, N_D) - I_{Auger}(V_{adj}, w, N_D) - I_0 \left[e^{\frac{V_{adj}}{nV_{th}}} - 1 \right] - \frac{V_{adj}}{R_{SH}}$$

$$V_{adj} = V + IR_S$$

Cell Volume (width)

Bulk Doping

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Calculating Intrinsic Recombination

$$I = I_{ph} - I_{rad}(V_{adj}, w, N_D) - I_{Auger}(V_{adj}, w, N_D) - I_0 \left[e^{\frac{V_{adj}}{nV_{th}}} - 1 \right] - \frac{V_{adj}}{R_{SH}}$$

$$np = n_{i,eff}^2 e^{\frac{\Delta\phi}{V_{th}}}$$

Kerr, M., and Cuevas, A. *Journal of Applied Physics* 91.4 (2002): 2473-2480.

$$n_i = 1.541 \times 10^{15} T^{1.712} e^{\frac{qE_g}{2kT}}$$

Richter, A, et al. *Phys Rev. B*—86.16 (2012): 165202.

$$R_{rad} = B_{low} n_{i,0}^2 e^{\frac{\Delta\phi}{kT}} (1 - f_{PR})$$

$$g_{exh} = 1 + (g_{exh,max} - 1) \frac{1}{(n + p)^{\alpha_{Auger}}}$$

$$\Delta\phi = V + JR_{S,ext}$$

Niewelt, T., et al. *SOLMAT* 235 (2022): 111467.

Black, L., and Macdonald, D., *SOLMAT* 234 (2022): 111428.

$$\Delta_{\chi ce} = \Delta_{\chi ce.1} \times \Delta_{\chi ce.2} \times$$

Black, L., et al. *SOLMAT* 295 (2026): 113985.

$$9.71 \times 10^{-32} \left(1 + 2e^{\frac{qhw_{eeh}}{kT}} \right)^{-1}$$

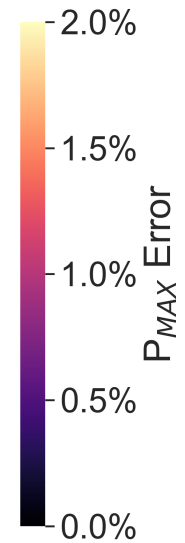
Hamer, P, et al. "The intrinsic adjusted single-diode model: Solid State Physics meets accurate yield simulation." *Solar Energy Materials and Solar Cells* 300 (2026): 114218.

Cell Fitting – Quokka (P_{MAX})



Datasheet Fit

Temperature (°C)	100.0	200.0	400.0	600.0	800.0	1000.0	1100.0
15.0	0.31%	0.23%	0.29%	0.23%	0.18%	0.14%	0.12%
20.0	0.27%	0.19%	0.24%	0.17%	0.11%	0.06%	0.03%
25.0	0.24%	0.18%	0.18%	0.10%	0.03%	0.00%	0.05%
30.0	0.24%	0.14%	0.11%	0.02%	0.05%	0.11%	0.10%
35.0	0.21%	0.11%	0.04%	0.07%	0.15%	0.21%	0.24%
40.0	0.21%	0.06%	0.03%	0.14%	0.27%	0.32%	0.36%
45.0	0.22%	0.00%	0.15%	0.30%	0.39%	0.45%	0.49%
50.0	0.23%	0.09%	0.27%	0.38%	0.55%	0.62%	0.63%
55.0	0.26%	0.19%	0.40%	0.58%	0.71%	0.78%	0.75%



Cell Fitting – Quokka (P_{MAX})

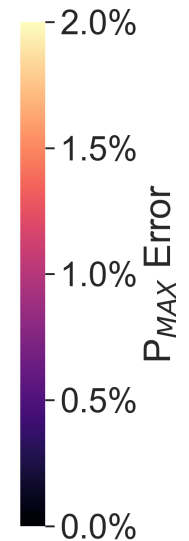


Datasheet Fit

Temperature (°C)	100.0	200.0	400.0	600.0	800.0	1000.0	1100.0
15.0	0.31%	0.23%	0.29%	0.23%	0.18%	0.14%	0.12%
20.0	0.27%	0.19%	0.24%	0.17%	0.11%	0.06%	0.03%
25.0	0.24%	0.18%	0.18%	0.10%	0.03%	0.00%	0.05%
30.0	0.24%	0.14%	0.11%	0.02%	0.05%	0.11%	0.10%
35.0	0.21%	0.11%	0.04%	0.07%	0.15%	0.21%	0.24%
40.0	0.21%	0.06%	0.03%	0.14%	0.27%	0.32%	0.36%
45.0	0.22%	0.00%	0.15%	0.30%	0.39%	0.45%	0.49%
50.0	0.23%	0.09%	0.27%	0.38%	0.55%	0.62%	0.63%
55.0	0.26%	0.19%	0.40%	0.58%	0.71%	0.78%	0.75%

Single-Diode Fit

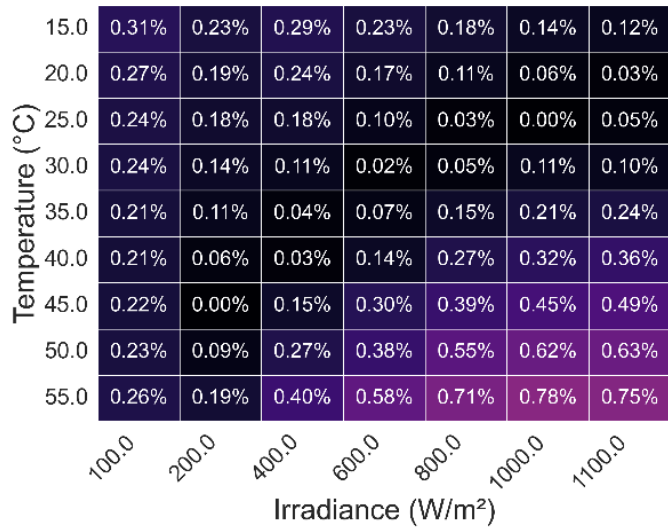
Temperature (°C)	100.0	200.0	400.0	600.0	800.0	1000.0	1100.0
15.0	1.76%	1.29%	0.86%	0.67%	0.57%	0.51%	0.49%
20.0	1.81%	1.30%	0.88%	0.68%	0.58%	0.52%	0.50%
25.0	1.87%	1.34%	0.89%	0.70%	0.60%	0.54%	0.52%
30.0	1.90%	1.37%	0.92%	0.72%	0.62%	0.56%	0.54%
35.0	1.97%	1.42%	0.94%	0.74%	0.64%	0.58%	0.56%
40.0	2.02%	1.46%	0.95%	0.75%	0.66%	0.60%	0.58%
45.0	2.07%	1.45%	0.99%	0.78%	0.67%	0.62%	0.60%
50.0	2.15%	1.52%	1.01%	0.79%	0.69%	0.64%	0.62%
55.0	2.21%	1.57%	1.02%	0.81%	0.71%	0.65%	0.63%



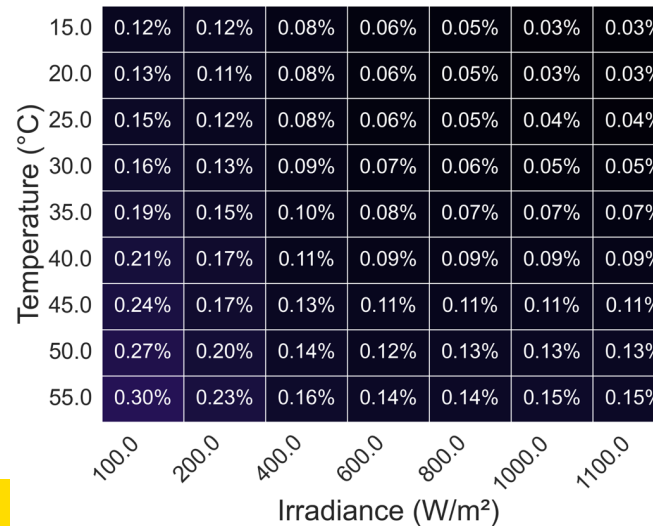
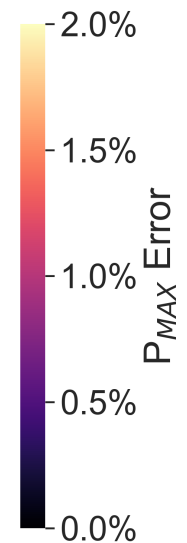
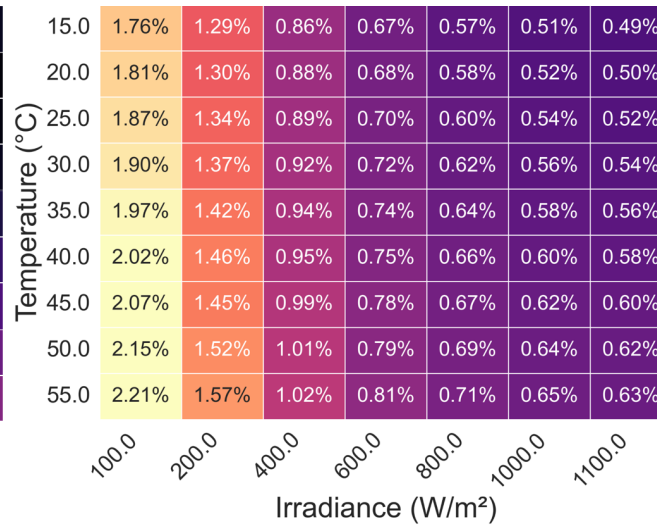
Cell Fitting – Quokka (P_{MAX})



Datasheet Fit



Single-Diode Fit



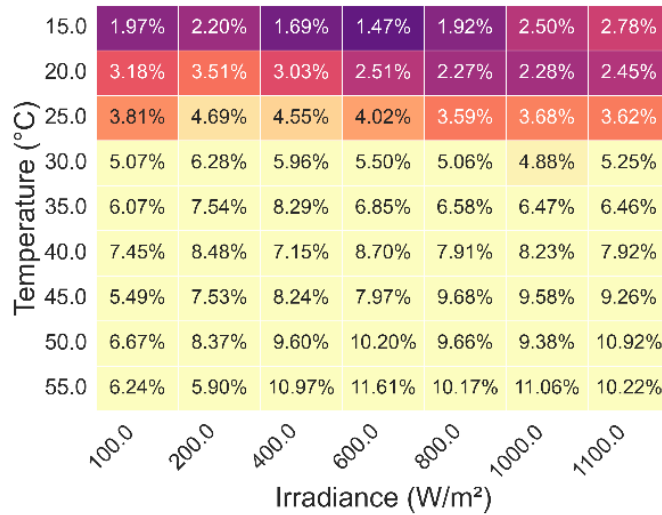
Adjusted Model

<https://www.quokka3.com/>

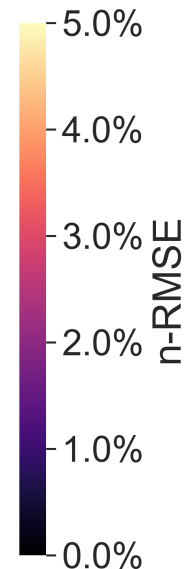
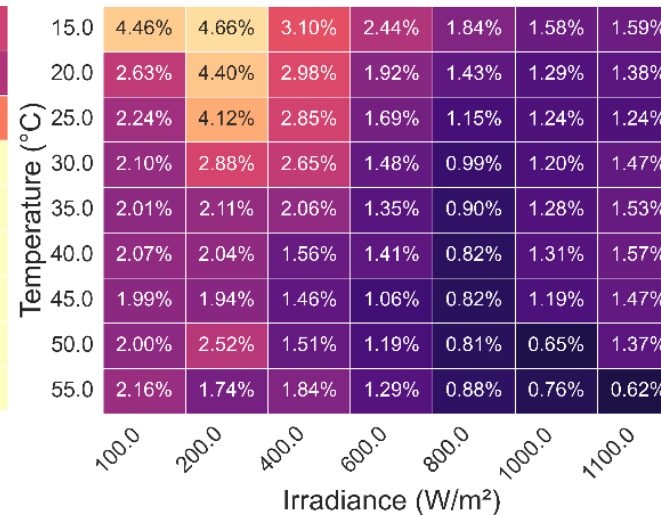
Cell Fitting – Quokka (n-RMSE)



Datasheet Fit



Single-Diode Fit

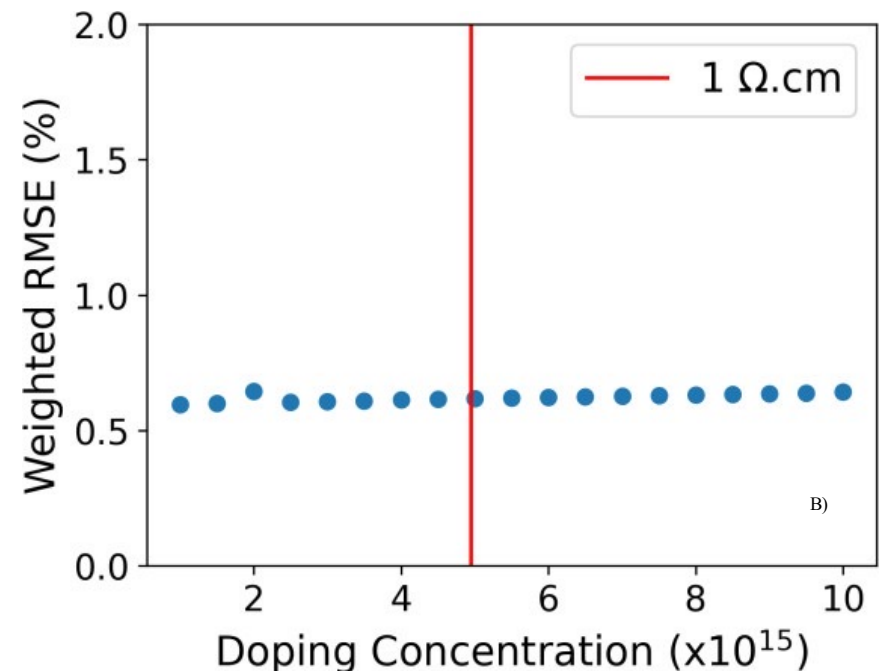
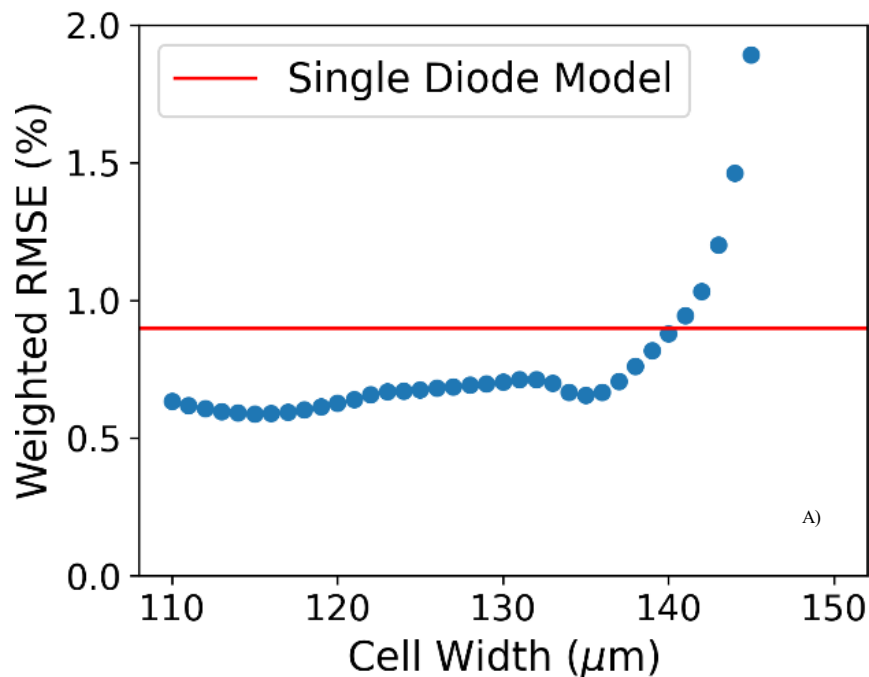


Adjusted Model

<https://www.quokka3.com/>

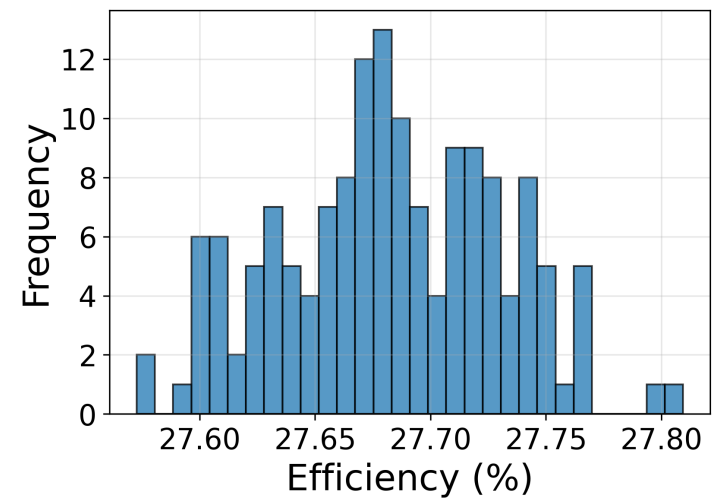
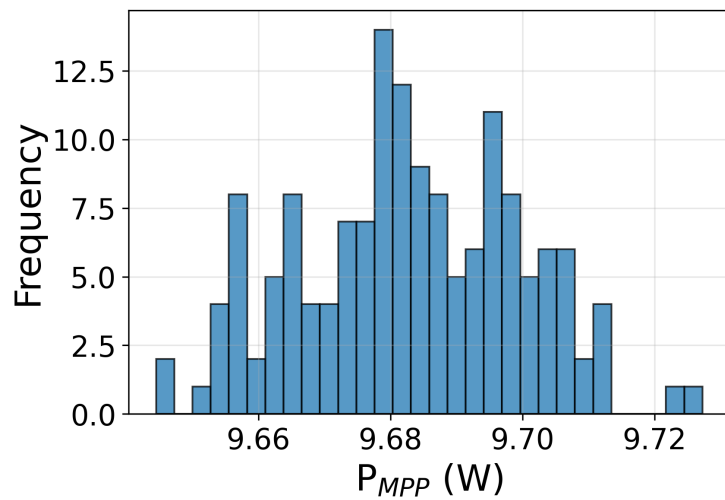
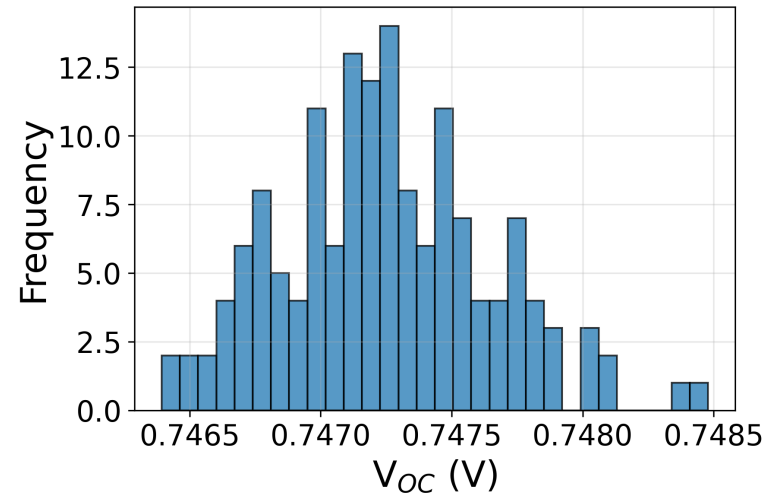
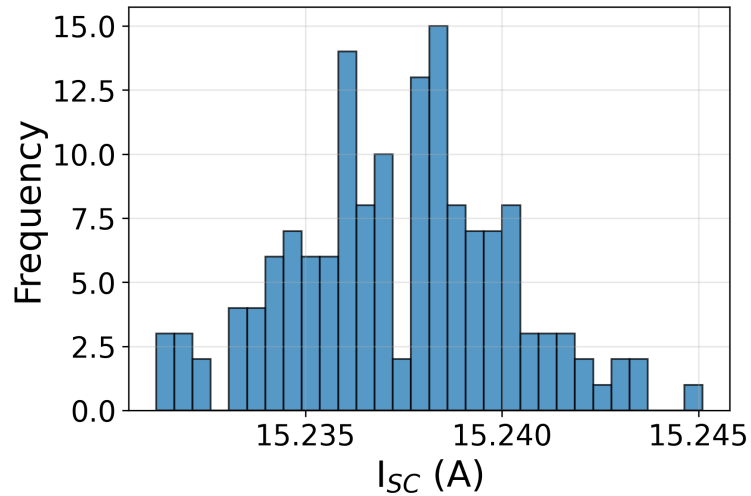
Fitting to Real Cells

- Real Cells – Hard to know actual cell thickness and doping
- We can instead use them as fitting parameters
- Bulk Doping has minimal impact

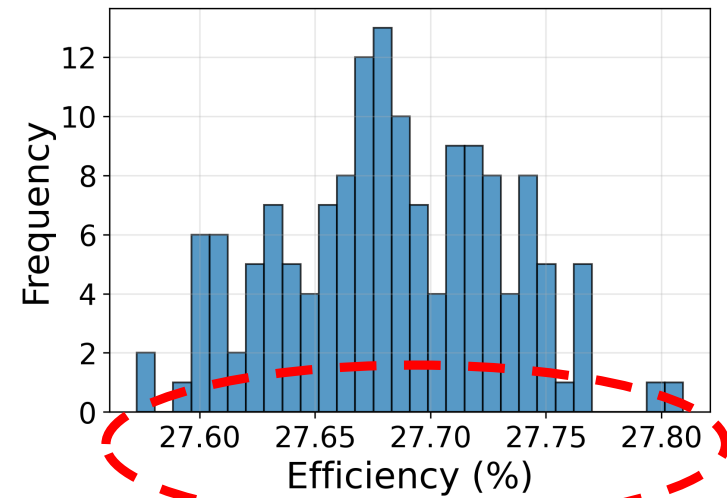
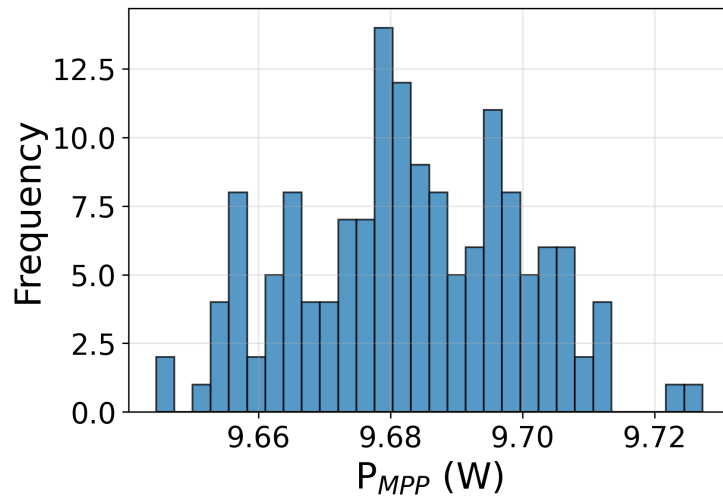
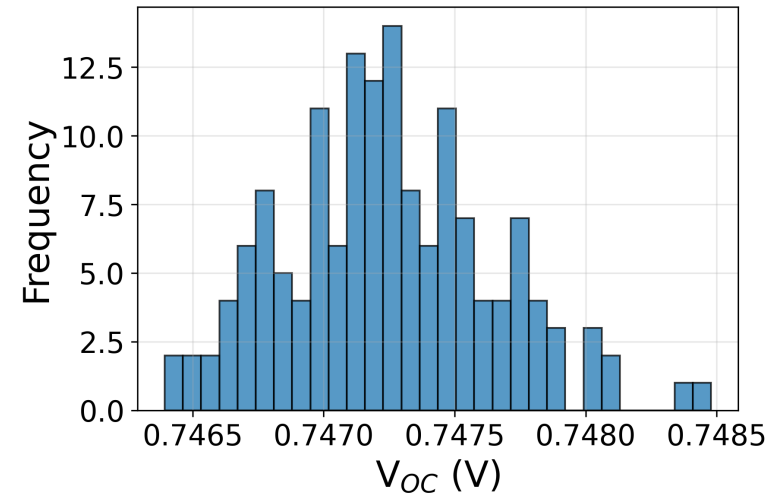
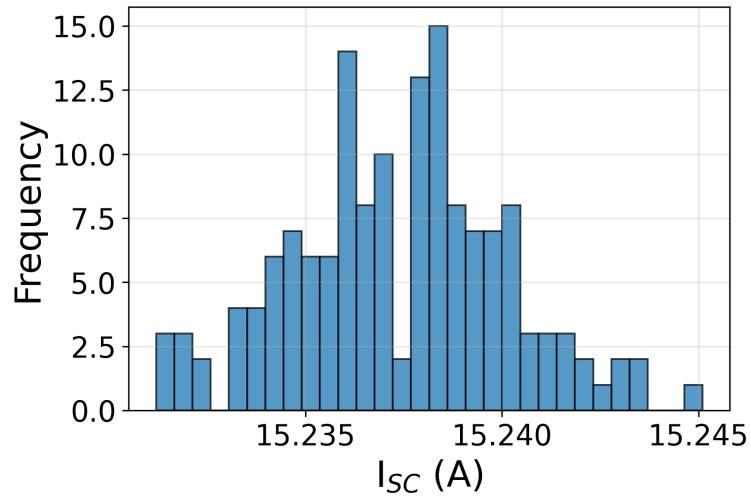


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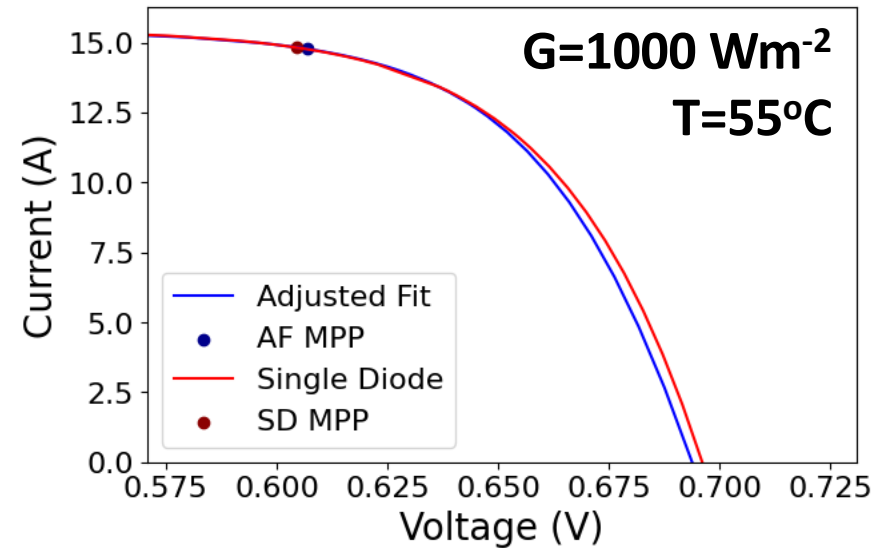
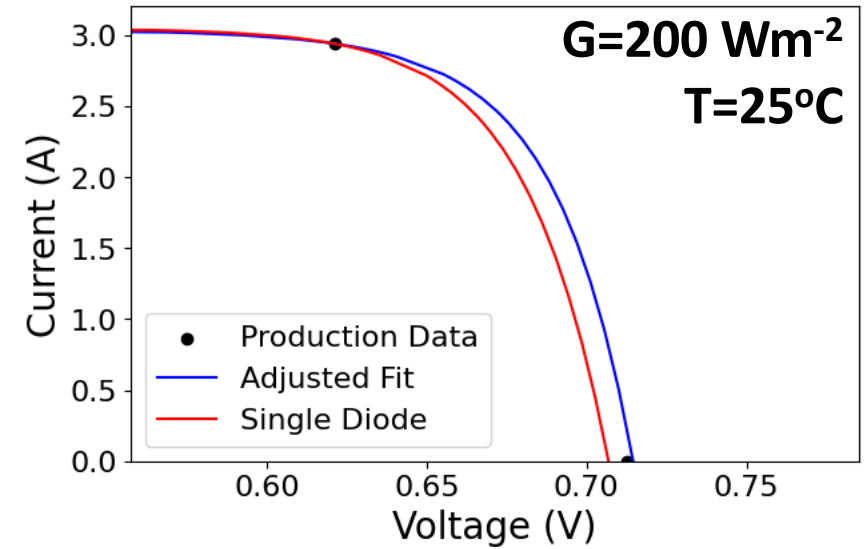
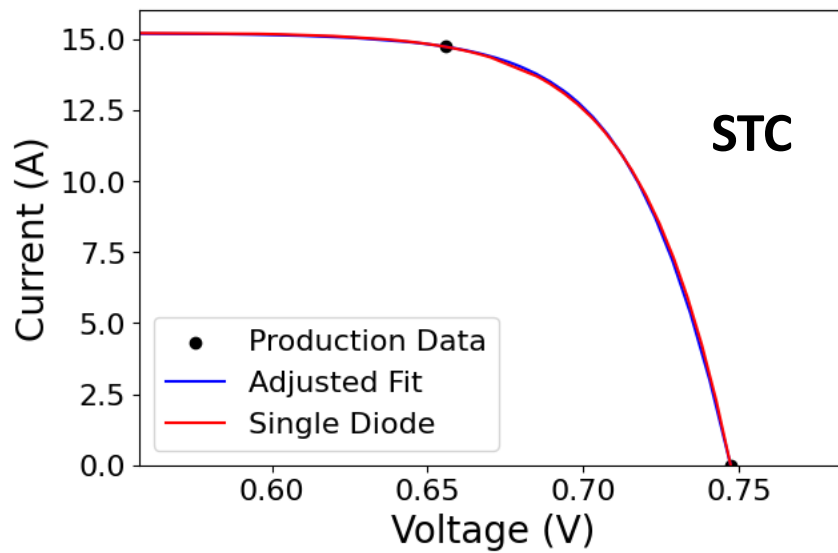
Pilot Production Data



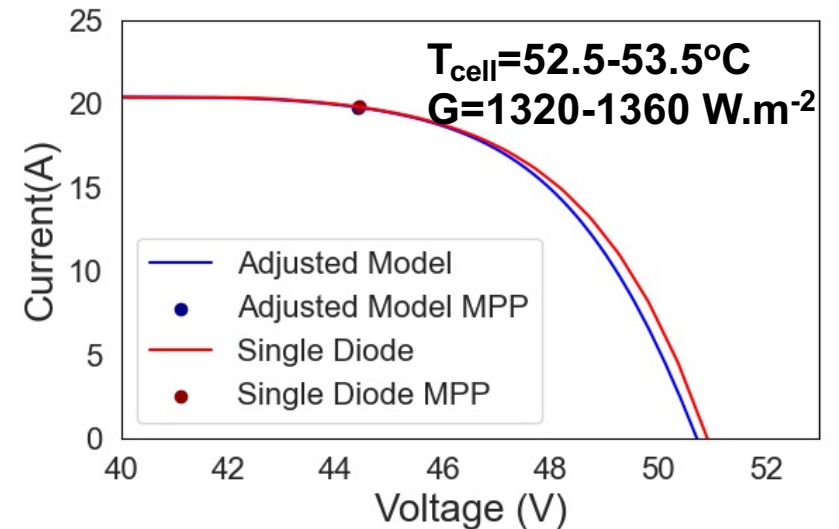
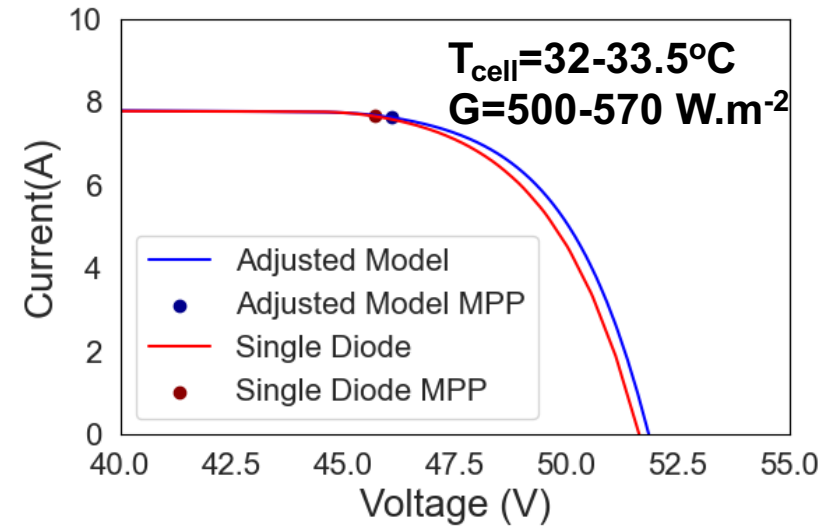
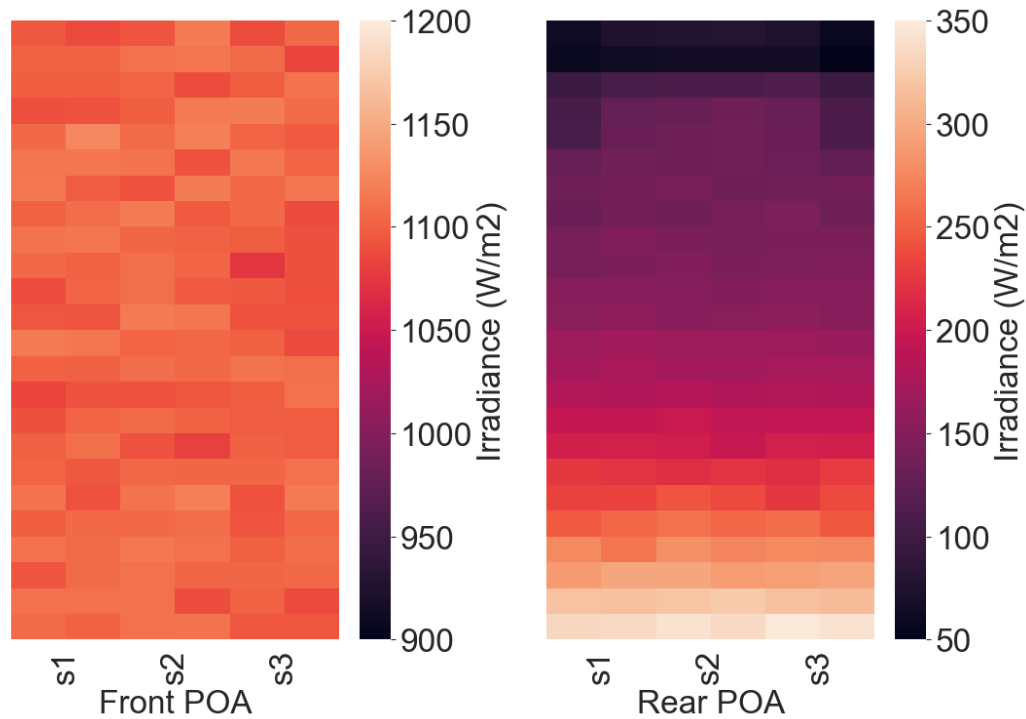
Pilot Production Data



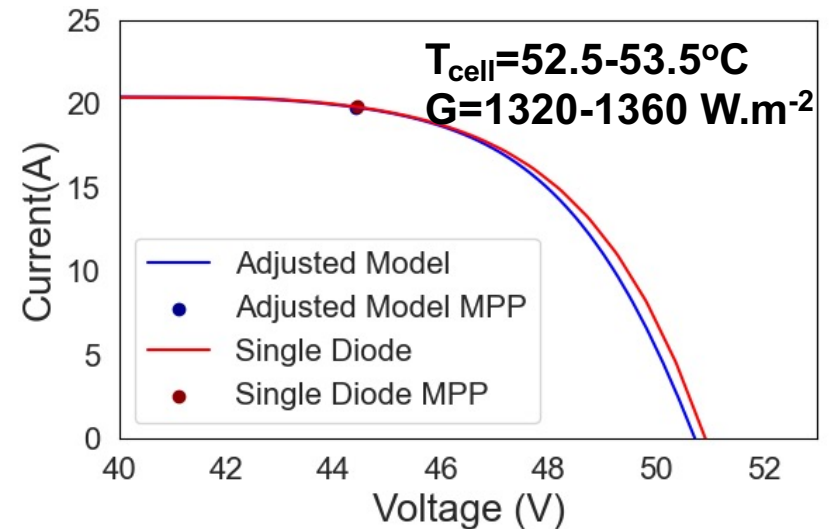
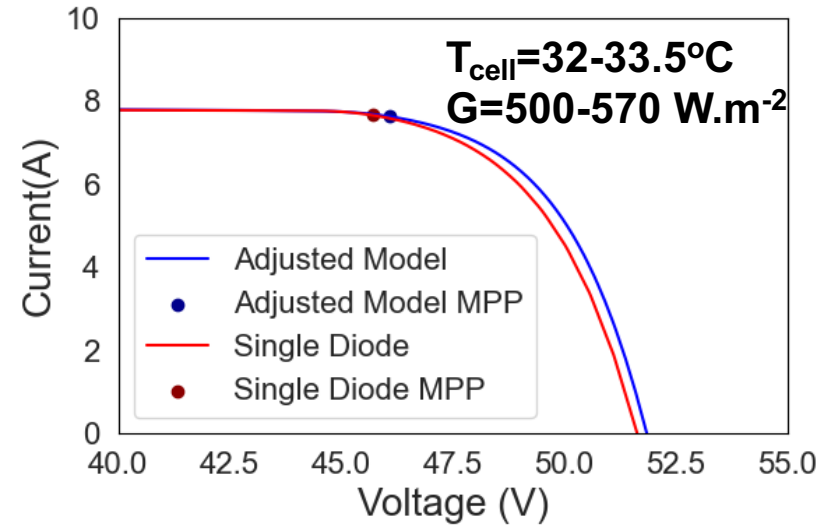
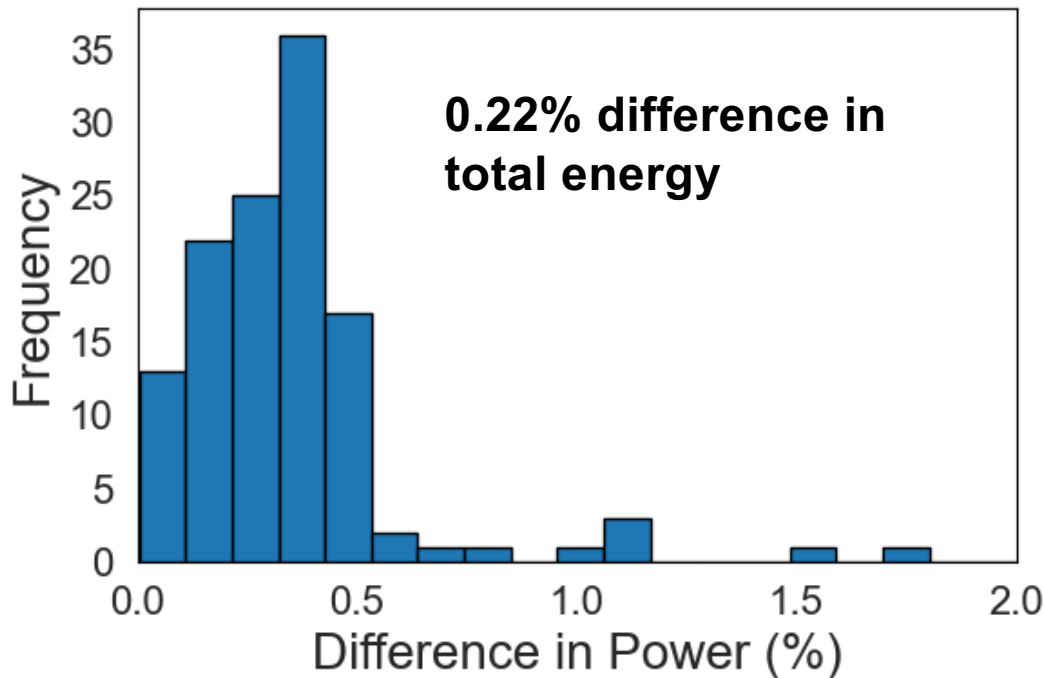
Fitting Results



Convert to Module - SunSolve

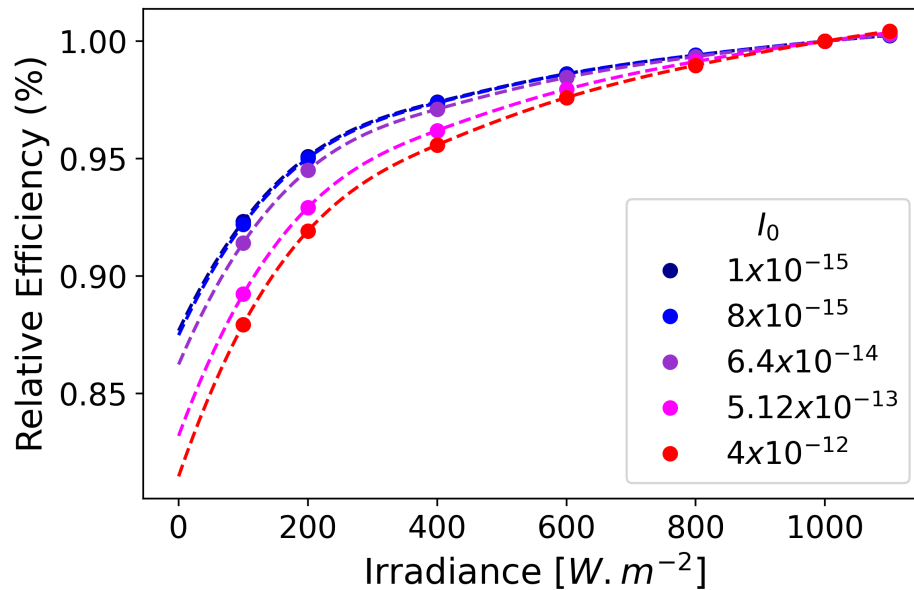


Convert to Module - SunSolve

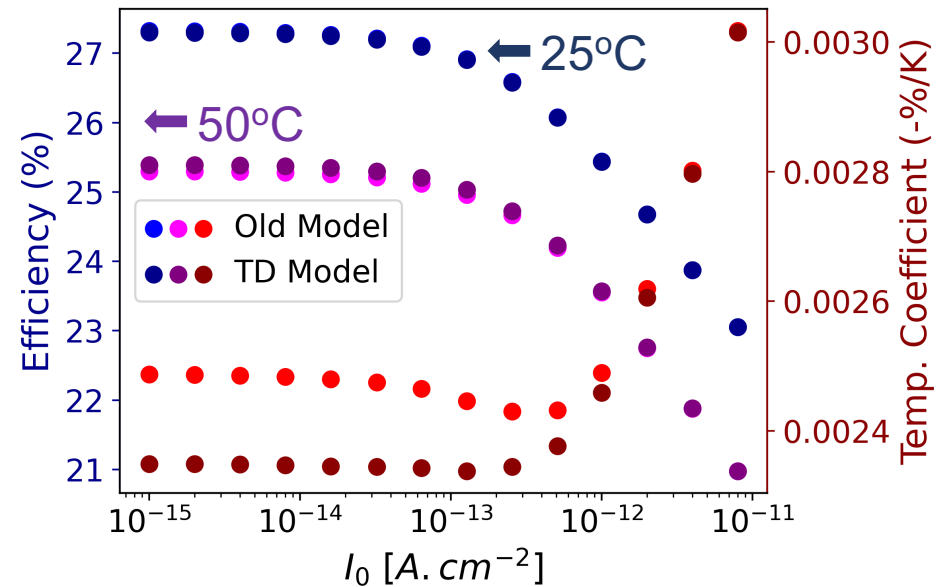


Implications of the Model

Low Light Performance



Temperature Performance



I_0 = the dark saturation current of the residual diode

Summary and acknowledgement

- Silicon solar cells are rapidly approaching the intrinsic limit
- Explicitly accounting for intrinsic recombination allows more accurate fitting of the *entire* IV curve
- This has implications for simulations of V_{OC} and under mismatch conditions

We want to hear about PV modelling challenges!

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LONGI

ARENA



Australian Government

Australian Renewable
Energy Agency



ACAP

Foresight PV